

SBS 1.1-COMPLIANT GAS GAUGE and PROTECTION ENABLED WITH IMPEDANCE TRACK™

FEATURES

- **Next Generation Patented Impedance Track™ Technology Accurately Measures Available Charge in Li-Ion and Li-Polymer Batteries**
 - Better Than 1% Error Over Lifetime of the Battery
- **Supports the Smart Battery Specification SBS V1.1**
- **Flexible Configuration for 2 to 4 Series Li-Ion and Li-Polymer Cells**
- **Powerful 8-Bit RISC CPU With Ultra-Low Power Modes**
- **Full Array of Programmable Protection Features**
 - Voltage, Current, and Temperature
- **Supports SHA-1 Authentication**
- **Complete Battery Protection and Gas Gauge Solution in one Package**
- **Small 44-Pin TSSOP (DBT) package**

APPLICATIONS

- **Notebook PCs**
- **Medical and Test Equipment**
- **Portable Instrumentation**

DESCRIPTION

The bq20z95 SBS-compliant gas gauge and protection IC is a single IC solution designed for battery-pack or in-system installation. The bq20z95 measures and maintains an accurate record of available charge in Li-ion or Li-polymer batteries using its integrated high-performance analog peripherals, monitors capacity change, battery impedance, open-circuit voltage, and other critical parameters of the battery pack as well and reports the information to the system host controller over a serial-communication bus. Together with the integrated analog front-end (AFE) short-circuit and overload protection, the bq20z95 maximizes functionality and safety while minimizing external component count, cost, and size in smart battery circuits.

The implemented Impedance Track™ gas gauging technology continuously analyzes the battery impedance, resulting in superior gas-gauging accuracy. This enables remaining capacity to be calculated with discharge rate, temperature, and cell aging all accounted for during each stage of every cycle with high accuracy.

AVAILABLE OPTIONS

| T_A | PACKAGE ⁽¹⁾ | |
|---------------|---------------------------|----------------------------------|
| | 44-PIN TSSOP (DBT) Tube | 44-PIN TSSOP (DBT) Tape and Reel |
| –40°C to 85°C | bq20z95DBT ⁽²⁾ | bq20z95DBTR ⁽³⁾ |

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) A single tube quantity is 50 units.

(3) A single reel quantity is 2000 units



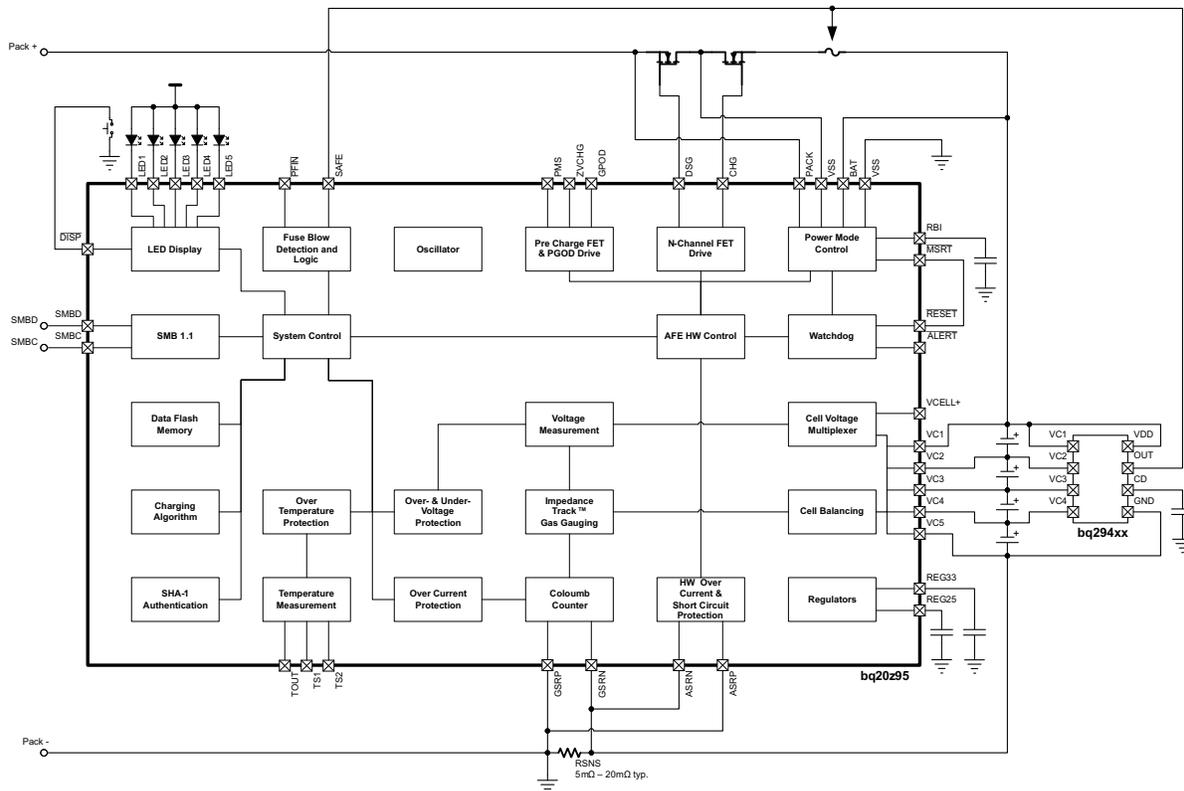
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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

SYSTEM PARTITIONING DIAGRAM



bq20z95
DBT Package
(TOP VIEW)

| | | | |
|--------|----|----|-------|
| DSG | 1 | 44 | CHG |
| PACK | 2 | 43 | BAT |
| VCC | 3 | 42 | VC1 |
| ZVCHG | 4 | 41 | VC2 |
| GPOD | 5 | 40 | VC3 |
| PMS | 6 | 39 | VC4 |
| VSS | 7 | 38 | VC5 |
| REG33 | 8 | 37 | ASRP |
| TOUT | 9 | 36 | ASRN |
| VCELL+ | 10 | 35 | RESET |
| ALERT | 11 | 34 | VSS |
| NC | 12 | 33 | RBI |
| TS1 | 13 | 32 | REG25 |
| TS2 | 14 | 31 | VSS |
| PRES | 15 | 30 | MRST |
| PFIN | 16 | 29 | GSRN |
| SAFE | 17 | 28 | GSRP |
| SMBD | 18 | 27 | LED5 |
| NC | 19 | 26 | LED4 |
| SMBC | 20 | 25 | LED3 |
| DISP | 21 | 24 | LED2 |
| VSS | 22 | 23 | LED1 |

TERMINAL FUNCTIONS

| TERMINAL | | I/O ⁽¹⁾ | DESCRIPTION |
|----------|--------|--------------------|--|
| NO. | NAME | | |
| 1 | DSG | O | High side N-chan discharge FET gate drive |
| 2 | PACK | IA, P | Battery pack input voltage sense input. It also serves as device wake up when device is in shutdown mode. |
| 3 | VCC | P | Positive device supply input. Connect to the center connection of the CHG FET and DSG FET to ensure device supply either from battery stack or battery pack input |
| 4 | ZVCHG | O | P-chan pre-charge FET gate drive |
| 5 | GPOD | OD | High voltage general purpose open drain output. Can be configured to be used in pre-charge condition |
| 6 | PMS | I | Pre-charge mode setting input. Connect to PACK to enable 0v pre-charge using charge FET connected at CHG pin. Connect to VSS to disable 0V pre-charge using charge FET connected at CHG pin. |
| 7 | VSS | P | Negative device power supply input. Connect all VSS pins together for operation of device |
| 8 | REG33 | P | 3.3V regulator output. Connect at least a 2.2μF capacitor to REG33 and VSS |
| 9 | TOUT | P | Thermistor bias supply output |
| 10 | VCELL+ | - | Internal cell voltage multiplexer and amplifier output. Connect a 0.1μF capacitor to VCELL+ and VSS |
| 11 | ALERT | I/OD | Alert output. In case of short circuit condition, overload condition and watchdog time out this pin will be triggered. |
| 12 | NC | - | Not connected |
| 13 | TS1 | IA | Temperature sensor 1 input |
| 14 | TS2 | IA | Temperature sensor 2 input |
| 15 | PRES | I/OD | System / Host present input. Pull up to TOUT |
| 16 | PFIN | I/OD | Fuse blow detection input |
| 17 | SAFE | I/OD | blow fuse signal output |
| 18 | SMBD | I/OD | SMBus data line |
| 19 | NC | - | Not connected |
| 20 | SMBC | I/OD | SMBus clock line |
| 21 | DISP | I/OD | Display enable input |
| 22 | VSS | P | Negative device power supply input. Connect all VSS pins together for operation of device |
| 23 | LED1 | I | LED 1 current sink input |
| 24 | LED2 | I | LED 2 current sink input |
| 25 | LED3 | I | LED 3 current sink input |
| 26 | LED4 | I | LED 4 current sink input |
| 27 | LED5 | I | LED 5 current sink input |
| 28 | GSRP | IA | Coulomb counter differential input. Connect to one side of the sense resistor |
| 29 | GSRN | IA | Coulomb counter differential input. Connect to one side of the sense resistor |
| 30 | MRST | I | Reset input for internal CPU core. connect to RESET for correct operation of device |
| 31 | VSS | P | Negative device power supply input. Connect all VSS pins together for operation of device |
| 32 | REG25 | P | 2.5V regulator output. Connect at least a 1μF capacitor to REG25 and VSS |
| 33 | RBI | P | RAM backup input. Connect a capacitor to this pin and VSS to protect loss of RAM data in case of short circuit condition |
| 34 | VSS | P | Negative device power supply input. Connect all VSS pins together for operation of device |
| 35 | RESET | O | Reset output. Connect to MRST. |
| 36 | ASRN | IA | Short circuit and overload detection differential input. Connect to sense resistor |
| 37 | ASRP | IA | Short circuit and overload detection differential input. Connect to sense resistor |
| 38 | VC5 | IA, P | Cell voltage sense input and cell balancing input for the negative voltage of the bottom cell in cell stack. |
| 39 | VC4 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the bottom cell and the negative voltage of the second lowest cell in cell stack. |

(1) I = Input, IA = Analog input, I/O = Input/output, I/OD = Input/Open-drain output, O = Output, OA = Analog output, P = Power

TERMINAL FUNCTIONS (continued)

| TERMINAL | | I/O ⁽¹⁾ | DESCRIPTION |
|----------|------|--------------------|--|
| NO. | NAME | | |
| 40 | VC3 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the second lowest cell in cell stack and the negative voltage of the second highest cell in 4 cell applications. |
| 41 | VC2 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the second highest cell and the negative voltage of the highest cell in 4 cell applications. Connect to VC3 in 2 cell stack applications |
| 42 | VC1 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the highest cell in cell stack in 4 cell applications. Connect to VC2 in 3 or 2 cell stack applications |
| 43 | BAT | I, P | Battery stack voltage sense input |
| 44 | CHG | O | High side N-chan charge FET gate drive |

Absolute Maximum RatingsOver Operating Free-Air Temperature (unless otherwise noted) ⁽¹⁾

| | DESCRIPTION | PIN | UNIT |
|------------------|--|--|--|
| V _{SS} | Supply voltage range | VBAT, VCC | –0.3 V to 34 V |
| | | PACK, PMS | –0.3 V to 34 V |
| | | VC(n)-VC(n+1); n = 1, 2, 3, 4 | –0.3 V to 8.5 V |
| | | VC1, VC2, VC3, VC4 | –0.3 V to 34 V |
| | | VC5 | –0.3 V to 1 V |
| V _{IN} | Input voltage range | PFIN, SMBD, SMBC, LED1, LED2, LED3, LED4, LED5, DISP | –0.3 V to 6 V |
| | | TS1, TS2, SAFE, VCELL+, PRES, ALERT | –0.3 V to V _(REG25) + 0.3 V |
| | | MRST, GSRN, GSRP, RBI | –0.3 V to V _(REG25) + 0.3 V |
| | | ASRN, ASRP | –1 V to 1 V |
| V _{OUT} | Output voltage range | DSG, CHG, GPOD | –0.3 V to 34 V |
| | | ZVCHG | –0.3 V to V _(BAT) |
| | | TOUT, ALERT, REG33 | –0.3 V to 6 V |
| | | RESET | –0.3 V to 7 V |
| | | REG25 | –0.3 V to 2.75 V |
| I _{SS} | Maximum combined sink current for input pins | PRES, PFIN, SMBD, SMBC, LED5, LED4, LED3, LED2, LED1 | 50 mA |
| T _A | Operating free-air temperature range | | –40°C to 85°C |
| T _F | Functional temperature | | –40°C to 100°C |
| T _{stg} | Storage temperature range | | –65°C to 150°C |

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | PIN | MIN | NOM | MAX | UNIT |
|------------------------|--|----------------------------|------|-----|------------------|------|
| V _{SS} | Supply voltage | VCC, VBAT | 4.5 | | 25 | V |
| V _(STARTUP) | Minimum startup voltage | VCC, BAT, PACK | 5.5 | | | V |
| V _{IN} | Input Voltage Range | VC(n)-VC(n+1); n = 1,2,3,4 | 0 | | 5 | V |
| | | VC1, VC2, VC3, VC4 | 0 | | V _{SUP} | V |
| | | VC5 | 0 | | 0.5 | V |
| | | ASRN, ASRP | -0.5 | | 0.5 | V |
| | | PACK, PMS | 0 | | 25 | V |
| V _(GPOD) | Output Voltage Range | GPOD | 0 | | 25 | V |
| A _(GPOD) | Drain Current ⁽¹⁾ | GPOD | | | 1 | mA |
| C _(REG25) | 2.5V LDO Capacitor | REG25 | 1 | | | μF |
| C _(REG33) | 3.3V LDO Capacitor | REG33 | 2.2 | | | μF |
| C _(VCELL+) | Cell Voltage Output Capacitor | VCELL+ | 0.1 | | | μF |
| C _(PACK) | PACK input block resistor ⁽²⁾ | PACK | 1 | | | kΩ |

(1) Use an external resistor to limit the current to GPOD to 1mA in high voltage application.

(2) Use an external resistor to limit the inrush current PACK pin required.

Electrical Characteristics

 over operating free-air temperature range (unless otherwise noted), T_A = -40°C to 85°C, V_(REG25) = 2.41 V to 2.59 V, V_(BAT) = 14 V, C_(REG25) = 1 μF, C_(REG33) = 2.2 μF; typical values at T_A = 25°C (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---|--|------|------|------|------|
| SUPPLY CURRENT | | | | | | |
| I _(NORMAL) | Firmware running | | | 550 | | μA |
| I _(SLEEP) | Sleep Mode | CHG FET on; DSG FET on | | 124 | | μA |
| | | CHG FET off; DSG FET on | | 90 | | μA |
| | | CHG FET off; DSG FET off | | 52 | | μA |
| I _(SHUTDOWN) | Shutdown Mode | | 0.1 | | 1 | μA |
| SHUTDOWN WAKE; T_A = 25°C (unless otherwise noted) | | | | | | |
| I _(PACK) | Shutdown exit at V _{STARTUP} threshold | | | | 1 | μA |
| SRx WAKE FROM SLEEP; T_A = 25°C (unless otherwise noted) | | | | | | |
| V _(WAKE) | Positive or negative wake threshold with 1.00 mV, 2.25 mV, 4.5 mV and 9 mV programmable options | | 1.25 | | 10 | mV |
| V _(WAKE_ACR) | Accuracy of V _(WAKE) | V _(WAKE) = 1 mV; I _(WAKE) = 0, RSNS1 = 0, RSNS0 = 1; | -0.7 | | 0.7 | mV |
| | | V _(WAKE) = 2.25 mV; I _(WAKE) = 1, RSNS1 = 0, RSNS0 = 1; I _(WAKE) = 0, RSNS1 = 1, RSNS0 = 0; | -0.8 | | 0.8 | |
| | | V _(WAKE) = 4.5 mV; I _(WAKE) = 1, RSNS1 = 1, RSNS0 = 1; I _(WAKE) = 0, RSNS1 = 1, RSNS0 = 0; | -1.0 | | 1.0 | |
| | | V _(WAKE) = 9 mV; I _(WAKE) = 1, RSNS1 = 1, RSNS0 = 1; | -1.4 | | 1.4 | |
| V _(WAKE_TCO) | Temperature drift of V _(WAKE) accuracy | | | 0.5 | | %/°C |
| t _(WAKE) | Time from application of current and wake of bq8040 | | | 1 | 10 | ms |
| POWER-ON RESET | | | | | | |
| V _{IT-} | Negative-going voltage input | Voltage at REG25 pin | 1.70 | 1.80 | 1.90 | V |
| V _{hys} | Hysteresis | V _{IT+} - V _{IT-} | 50 | 150 | 250 | mV |
| t _{RST} | RESET active low time | active low time after power up or watchdog reset | 100 | 250 | 560 | μs |
| WATCHDOG TIMER | | | | | | |
| t _{WDTINT} | Watchdog start up detect time | | 250 | 500 | 1000 | ms |

Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted), $T_A = -40^\circ\text{C}$ to 85°C , $V_{(\text{REG25})} = 2.41\text{ V}$ to 2.59 V , $V_{(\text{BAT})} = 14\text{ V}$, $C_{(\text{REG25})} = 1\text{ }\mu\text{F}$, $C_{(\text{REG33})} = 2.2\text{ }\mu\text{F}$; typical values at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|--|---|------------------------------------|------------------------------------|------------------------------------|---------------|
| t_{WDWT} | Watchdog detect time | | 50 | 100 | 150 | μs |
| 2.5V LDO; $I_{(\text{REG33OUT})} = 0\text{ mA}$; $T_A = 25^\circ\text{C}$ (unless otherwise noted) | | | | | | |
| $V_{(\text{REG25})}$ | Regulator output voltage | $4.5 < \text{VCC}$ or $\text{BAT} < 25\text{ V}$; $I_{(\text{REG25OUT})} \leq 16\text{ mA}$; $T_A = -40^\circ\text{C}$ to 100°C | 2.41 | 2.5 | 2.59 | V |
| $\Delta V_{(\text{REG25TEMP})}$ | Regulator output change with temperature | $I_{(\text{REG25OUT})} = 2\text{ mA}$; $T_A = -40^\circ\text{C}$ to 100°C | | ± 0.2 | | % |
| $\Delta V_{(\text{REG25LINE})}$ | Line regulation | $5.4 < \text{VCC}$ or $\text{BAT} < 25\text{ V}$; $I_{(\text{REG25OUT})} = 2\text{ mA}$ | | 3 | 10 | mV |
| $\Delta V_{(\text{REG25LOAD})}$ | Load Regulation | $0.2\text{ mA} \leq I_{(\text{REG25OUT})} \leq 2\text{ mA}$ | | 7 | 25 | mV |
| | | $0.2\text{ mA} \leq I_{(\text{REG25OUT})} \leq 16\text{ mA}$ | | 25 | 50 | |
| $I_{(\text{REG25MAX})}$ | Current Limit | drawing current until REG25 = 2 V to 0 V | 5 | 40 | 75 | mA |
| 3.3V LDO; $I_{(\text{REG25OUT})} = 0\text{ mA}$; $T_A = 25^\circ\text{C}$ (unless otherwise noted) | | | | | | |
| $V_{(\text{REG33})}$ | Regulator output voltage | $4.5 < \text{VCC}$ or $\text{BAT} < 25\text{ V}$; $I_{(\text{REG33OUT})} \leq 25\text{ mA}$; $T_A = -40^\circ\text{C}$ to 100°C | 3 | 3.3 | 3.6 | V |
| $\Delta V_{(\text{REG33TEMP})}$ | Regulator output change with temperature | $I_{(\text{REG33OUT})} = 2\text{ mA}$; $T_A = -40^\circ\text{C}$ to 100°C | | ± 0.2 | | % |
| $\Delta V_{(\text{REG33LINE})}$ | Line regulation | $5.4 < \text{VCC}$ or $\text{BAT} < 25\text{ V}$; $I_{(\text{REG33OUT})} = 2\text{ mA}$ | | 3 | 10 | mV |
| $\Delta V_{(\text{REG33LOAD})}$ | Load Regulation | $0.2\text{ mA} \leq I_{(\text{REG33OUT})} \leq 2\text{ mA}$ | | 7 | 17 | mV |
| | | $0.2\text{ mA} \leq I_{(\text{REG33OUT})} \leq 25\text{ mA}$ | | 40 | 100 | |
| $I_{(\text{REG33MAX})}$ | Current Limit | drawing current until REG33 = 3 V | 25 | 100 | 145 | mA |
| | | short REG33 to VSS, REG33 = 0 V | 12 | | 65 | |
| THERMISTOR DRIVE | | | | | | |
| $V_{(\text{TOUT})}$ | Output voltage | $I_{(\text{TOUT})} = 0\text{ mA}$; $T_A = 25^\circ\text{C}$ | | $V_{(\text{REG25})}$ | | V |
| $R_{\text{DS(on)}}$ | TOUT pass element resistance | $I_{(\text{TOUT})} = 1\text{ mA}$; $R_{\text{DS(on)}} = (V_{(\text{REG25})} - V_{(\text{TOUT})}) / 1\text{ mA}$; $T_A = -40^\circ\text{C}$ to 100°C | | 50 | 100 | Ω |
| VCELL+ HIGH VOLTAGE TRANSLATION | | | | | | |
| $V_{(\text{VCELL+OUT})}$ | Translation output | $\text{VC}(n) - \text{VC}(n+1) = 0\text{ V}$; $T_A = -40^\circ\text{C}$ to 100°C | 0.950 | 0.975 | 1 | V |
| | | $\text{VC}(n) - \text{VC}(n+1) = 4.5\text{ V}$; $T_A = -40^\circ\text{C}$ to 100°C | 0.275 | 0.3 | 0.375 | |
| internal AFE reference voltage ; $T_A = -40^\circ\text{C}$ to 100°C | | 0.965 | 0.975 | 0.985 | | |
| Voltage at PACK pin; $T_A = -40^\circ\text{C}$ to 100°C | | $0.98 \times V_{(\text{PACK})}/18$ | $V_{(\text{PACK})}/18$ | $1.02 \times V_{(\text{PACK})}/18$ | | |
| $V_{(\text{VCELL+REF})}$ | | | | | | |
| $V_{(\text{VCELL+PACK})}$ | | Voltage at PACK pin; $T_A = -40^\circ\text{C}$ to 100°C | $0.98 \times V_{(\text{PACK})}/18$ | $V_{(\text{PACK})}/18$ | $1.02 \times V_{(\text{PACK})}/18$ | |
| $V_{(\text{VCELL+BAT})}$ | | Voltage at BAT pin; $T_A = -40^\circ\text{C}$ to 100°C | $0.98 \times V_{(\text{BAT})}/18$ | $V_{(\text{BAT})}/18$ | $1.02 \times V_{(\text{BAT})}/18$ | |
| CMMR | Common mode rejection ratio | VCELL+ | 40 | | | dB |
| K | Cell scale factor | $K = \{\text{VCELL+ output (VC5=0V}; \text{VC4=4.5V}) - \text{VCELL+ output (VC5=0V}; \text{VC4=0V})\} / 4.5$ | 0.147 | 0.150 | 0.153 | |
| | | $K = \{\text{VCELL+ output (VC2=13.5V}; \text{VC1=18V}) - \text{VCELL+ output (VC5=13.5V}; \text{VC1=13.5V})\} / 4.5$ | 0.147 | 0.150 | 0.153 | |
| $I_{(\text{VCELL+OUT})}$ | Drive Current to VCELL+ capacitor | $\text{VC}(n) - \text{VC}(n+1) = 0\text{ V}$; $\text{VCELL+} = 0\text{ V}$; $T_A = -40^\circ\text{C}$ to 100°C | 12 | 18 | | μA |
| $V_{(\text{VCELL+O})}$ | CELL offset error | CELL output ($\text{VC2} = \text{VC1} = 18\text{ V}$) - CELL output ($\text{VC2} = \text{VC1} = 0\text{ V}$) | -18 | -1 | 18 | mV |
| I_{VCnL} | VC(n) pin leakage current | VC1, VC2, VC3, VC4, VC5 = 3 V | -1 | 0.01 | 1 | μA |
| CELL BALANCING | | | | | | |
| R_{BAL} | internal cell balancing FET resistance | $R_{\text{DS(on)}}$ for internal FET switch at $V_{\text{DS}} = 2\text{ V}$; $T_A = 25^\circ\text{C}$ | 200 | 400 | 600 | Ω |
| HARDWARE SHORT CIRCUIT AND OVERLOAD PROTECTION; $T_A = 25^\circ\text{C}$ (unless otherwise noted) | | | | | | |

Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}\text{C}$ to 85°C , $V_{(\text{REG25})} = 2.41\text{ V}$ to 2.59 V , $V_{(\text{BAT})} = 14\text{ V}$, $C_{(\text{REG25})} = 1\text{ }\mu\text{F}$, $C_{(\text{REG33})} = 2.2\text{ }\mu\text{F}$; typical values at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|--|--|--------------------------|------|------|---------------|
| $V_{(\text{OL})}$ | OL detection threshold voltage accuracy | $V_{\text{OL}} = 25\text{ mV (min)}$ | 15 | 25 | 35 | mV |
| | | $V_{\text{OL}} = 100\text{ mV}$; $\text{RSNS} = 0, 1$ | 90 | 100 | 110 | |
| | | $V_{\text{OL}} = 205\text{ mV (max)}$ | 185 | 205 | 225 | |
| $V_{(\text{SCC})}$ | SCC detection threshold voltage accuracy | $V_{(\text{SCC})} = 50\text{ mV (min)}$ | 30 | 50 | 70 | mV |
| | | $V_{(\text{SCC})} = 200\text{ mV}$; $\text{RSNS} = 0, 1$ | 180 | 200 | 220 | |
| | | $V_{(\text{SCC})} = 475\text{ mV (max)}$ | 428 | 475 | 523 | |
| $V_{(\text{SCD})}$ | SCD detection threshold voltage accuracy | $V_{(\text{SCD})} = -50\text{ mV (min)}$ | -30 | -50 | -70 | mV |
| | | $V_{(\text{SCD})} = -200\text{ mV}$; $\text{RSNS} = 0, 1$ | -180 | -200 | -220 | |
| | | $V_{(\text{SCD})} = -475\text{ mV (max)}$ | -428 | -475 | -523 | |
| t_{da} | Delay time accuracy | | ± 15.25 | | | μs |
| t_{pd} | Protection circuit propagation delay | | 50 | | | μs |
| FET DRIVE CIRCUIT; $T_A = 25^{\circ}\text{C}$ (unless otherwise noted) | | | | | | |
| $V_{(\text{DSGON})}$ | DSG pin output on voltage | $V_{(\text{DSGON})} = V_{(\text{DSG})} - V_{(\text{PACK})}$; $V_{(\text{GS})} = 10\text{ M}\Omega$; DSG and CHG on; $T_A = -40^{\circ}\text{C}$ to 100°C | 8 | 12 | 16 | V |
| $V_{(\text{CHGON})}$ | CHG pin output on voltage | $V_{(\text{CHGON})} = V_{(\text{CHG})} - V_{(\text{BAT})}$; $V_{(\text{GS})} = 10\text{ M}\Omega$; DSG and CHG on; $T_A = -40^{\circ}\text{C}$ to 100°C | 8 | 12 | 16 | V |
| $V_{(\text{DSGOFF})}$ | DSG pin output off voltage | $V_{(\text{DSGOFF})} = V_{(\text{DSG})} - V_{(\text{PACK})}$ | | | 0.2 | V |
| $V_{(\text{CHGOFF})}$ | CHG pin output off voltage | $V_{(\text{CHGOFF})} = V_{(\text{CHG})} - V_{(\text{BAT})}$ | | | 0.2 | V |
| t_r | Rise time | $C_L = 4700\text{ pF}$; $V_{(\text{PACK})} \leq V_{(\text{DSG})} \leq V_{(\text{PACK})} + 4\text{ V}$ | | 400 | 1000 | μs |
| | | $C_L = 4700\text{ pF}$; $V_{(\text{BAT})} \leq \text{CHG} \leq V_{(\text{BAT})} + 4\text{ V}$ | | 400 | 1000 | |
| t_f | Fall time | $C_L = 4700\text{ pF}$; $V_{(\text{PACK})} + V_{(\text{DSGON})} \leq \text{DSG} \leq V_{(\text{PACK})} + 1\text{ V}$ | | 40 | 200 | μs |
| | | $C_L = 4700\text{ pF}$; $V_{(\text{BAT})} + V_{(\text{CHGON})} \leq \text{CHG} \leq V_{(\text{BAT})} + 1\text{ V}$ | | 40 | 200 | |
| $V_{(\text{ZVCHG})}$ | ZVCHG clamp voltage | BAT = 4.5 V | 3.3 | 3.5 | 3.7 | V |
| LOGIC; $T_A = -40^{\circ}\text{C}$ to 100°C (unless otherwise noted) | | | | | | |
| $R_{(\text{PULLUP})}$ | Internal pullup resistance | ALERT | 60 | 100 | 200 | k Ω |
| | | RESET | 1 | 3 | 6 | |
| V_{OL} | Logic low output voltage level | ALERT | | | 0.2 | V |
| | | RESET; $V_{(\text{BAT})} = 7\text{ V}$; $V_{(\text{REG25})} = 1.5\text{ V}$; $I_{(\text{RESET})} = 200\text{ }\mu\text{A}$ | | | 0.4 | |
| | | GPOD; $I_{(\text{GPOD})} = 50\text{ }\mu\text{A}$ | | | 0.6 | |
| LOGIC SMBC, SMBD, PFIN, PRES, SAFE, ALERT | | | | | | |
| V_{IH} | High-level input voltage | | 2.0 | | | V |
| V_{IL} | Low-level input voltage | | | | 0.8 | V |
| V_{OH} | Output voltage high ⁽¹⁾ | $I_L = -0.5\text{ mA}$ | $V_{\text{REG25}} - 0.5$ | | | V |
| V_{OL} | Low-level output voltage | PRES, PFIN, ALERT, $I_L = 7\text{ mA}$; | | | 0.4 | V |
| C_i | Input capacitance | | | 5 | | pF |
| $I_{(\text{SAFE})}$ | SAFE source currents | SAFE active, $\text{SAFE} = V_{(\text{REG25})} - 0.6\text{ V}$ | -3 | | | mA |
| $I_{\text{ikg}(\text{SAFE})}$ | SAFE leakage current | SAFE inactive | -0.2 | | 0.2 | μA |
| I_{ikg} | Input leakage current | | | | 1 | μA |
| ADC⁽²⁾ | | | | | | |
| | Input voltage range | TS1, TS2, using Internal V_{ref} | -0.2 | | 1 | V |
| | Conversion time | | | 31.5 | | ms |
| | Resolution (no missing codes) | | 16 | | | bits |
| | Effective resolution | | 14 | 15 | | bits |

(1) RC[0:7] bus

(2) Unless otherwise specified, the specification limits are valid at all measurement speed modes

Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted), $T_A = -40^\circ\text{C}$ to 85°C , $V_{(\text{REG25})} = 2.41\text{ V}$ to 2.59 V , $V_{(\text{BAT})} = 14\text{ V}$, $C_{(\text{REG25})} = 1\text{ }\mu\text{F}$, $C_{(\text{REG33})} = 2.2\text{ }\mu\text{F}$; typical values at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|--|-------|--------|--------|---------------------|
| Integral nonlinearity | | | | | ±0.03 | %FSR ⁽³⁾ |
| Offset error ⁽⁴⁾ | | | | 140 | 250 | μV |
| Offset error drift ⁽⁴⁾ | | $T_A = 25^\circ\text{C}$ to 85°C | | 2.5 | 18 | μV/°C |
| Full-scale error ⁽⁵⁾ | | | | ±0.1% | ±0.7% | |
| Full-scale error drift | | | | 50 | | PPM/°C |
| Effective input resistance ⁽⁶⁾ | | | 8 | | | MΩ |
| COULOMB COUNTER | | | | | | |
| Input voltage range | | | -0.20 | | 0.20 | V |
| Conversion time | | Single conversion | | 250 | | ms |
| Effective resolution | | Single conversion | 15 | | | bits |
| Integral nonlinearity | | -0.1 V to 0.20 V | | ±0.007 | ±0.034 | %FSR |
| | | -0.20 V to -0.1 V | | ±0.007 | | |
| Offset error ⁽⁷⁾ | | $T_A = 25^\circ\text{C}$ to 85°C | | 10 | | μV |
| Offset error drift | | | | 0.4 | 2.45 | μV/°C |
| Full-scale error ⁽⁸⁾⁽⁹⁾ | | | | ±0.35% | | |
| Full-scale error drift | | | | 150 | | PPM/°C |
| Effective input resistance ⁽¹⁰⁾ | | $T_A = 25^\circ\text{C}$ to 85°C | 2.5 | | | MΩ |
| INTERNAL TEMPERATURE SENSOR | | | | | | |
| $V_{(\text{TEMP})}$ | Temperature sensor voltage ⁽¹¹⁾ | | | -2.0 | | mV/°C |
| VOLTAGE REFERENCE | | | | | | |
| Output voltage | | | 1.215 | 1.225 | 1.230 | V |
| Output voltage drift | | | | 65 | | PPM/°C |
| HIGH FREQUENCY OSCILLATOR | | | | | | |
| $f_{(\text{OSC})}$ | Operating frequency | | | 4.194 | | MHz |
| $f_{(\text{EIO})}$ | Frequency error ⁽¹²⁾⁽¹³⁾ | | -3% | 0.25% | 3% | |
| | | $T_A = 20^\circ\text{C}$ to 70°C | -2% | 0.25% | 2% | |
| $t_{(\text{SXO})}$ | Start-up time ⁽¹⁴⁾ | | | 2.5 | 5 | ms |
| LOW FREQUENCY OSCILLATOR | | | | | | |
| $f_{(\text{LOSC})}$ | Operating frequency | | | 32.768 | | kHz |
| $f_{(\text{LEIO})}$ | Frequency error ⁽¹³⁾⁽¹⁵⁾ | | -2.5% | 0.25% | 2.5% | |
| | | $T_A = 20^\circ\text{C}$ to 70°C | -1.5% | 0.25% | 1.5% | |
| $t_{(\text{LSXO})}$ | Start-up time ⁽¹⁴⁾ | | | | 500 | μs |

(3) Full-scale reference

(4) Post-calibration performance and no I/O changes during conversion with SRN as the ground reference

(5) Uncalibrated performance. This gain error can be eliminated with external calibration.

(6) The A/D input is a switched-capacitor input. Since the input is switched, the effective input resistance is a measure of the average resistance.

(7) Post-calibration performance

(8) Reference voltage for the coulomb counter is typically $V_{\text{ref}}/3.969$ at $V_{(\text{REG25})} = 2.5\text{ V}$, $T_A = 25^\circ\text{C}$.

(9) Uncalibrated performance. This gain error can be eliminated with external calibration.

(10) The CC input is a switched capacitor input. Since the input is switched, the effective input resistance is a measure of the average resistance.

(11) $-53.7\text{ LSB}/^\circ\text{C}$

(12) The frequency error is measured from 4.194 MHz.

(13) The frequency drift is included and measured from the trimmed frequency at $V_{(\text{REG25})} = 2.5\text{ V}$, $T_A = 25^\circ\text{C}$

(14) The startup time is defined as the time it takes for the oscillator output frequency to be $\pm 3\%$

(15) The frequency error is measured from 32.768 kHz.

Data Flash Characteristics Over Recommended Operating Temperature and Supply Voltage

 Typical Values at $T_A = 25^\circ\text{C}$ and $V_{(\text{REG25})} = 2.5\text{ V}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT | |
|--|---|-----|------|------|--------|----|
| Data retention | See ⁽¹⁾ | 10 | | | Years | |
| Flash programming write-cycles | | 20k | | | Cycles | |
| $t_{(\text{ROWPROG})}$ Row programming time | | | | 2 | ms | |
| $t_{(\text{MASSERASE})}$ Mass-erase time | | | | 200 | ms | |
| $t_{(\text{PAGEERASE})}$ Page-erase time | | | | 20 | ms | |
| $I_{(\text{DDPROG})}$ Flash-write supply current | | | | 5 | 10 | mA |
| $I_{(\text{DDERASE})}$ Flash-erase supply current | | | | 5 | 10 | mA |
| RAM BACKUP | | | | | | |
| $I_{(\text{RB})}$ RB data-retention input current | $V_{(\text{RBI})} > V_{(\text{RBI})\text{MIN}}$, $V_{\text{REG25}} < V_{\text{IT-}}$, $T_A = 85^\circ\text{C}$ | | 1000 | 2500 | nA | |
| | $V_{(\text{RBI})} > V_{(\text{RBI})\text{MIN}}$, $V_{\text{REG25}} < V_{\text{IT-}}$, $T_A = 25^\circ\text{C}$ | | 90 | 220 | | |
| $V_{(\text{RB})}$ RB data-retention input voltage ⁽¹⁾ | | 1.7 | | | V | |

(1) Specified by design. Not production tested.

SMBus Timing Characteristics

 $T_A = -40^\circ\text{C}$ to 85°C Typical Values at $T_A = 25^\circ\text{C}$ and $V_{\text{REG25}} = 2.5\text{ V}$ (Unless Otherwise Noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|-----|------|------|---------------|
| $f_{(\text{SMB})}$ SMBus operating frequency | Slave mode, SMBC 50% duty cycle | 10 | | 100 | kHz |
| $f_{(\text{MAS})}$ SMBus master clock frequency | Master mode, No clock low slave extend | | 51.2 | | kHz |
| $t_{(\text{BUF})}$ Bus free time between start and stop (see Figure 1) | | 4.7 | | | μs |
| $t_{(\text{HD:STA})}$ Hold time after (repeated) start (see Figure 1) | | 4 | | | μs |
| $t_{(\text{SU:STA})}$ Repeated start setup time (see Figure 1) | | 4.7 | | | μs |
| $t_{(\text{SU:STO})}$ Stop setup time (see Figure 1) | | 4 | | | μs |
| $t_{(\text{HD:DAT})}$ Data hold time (see Figure 1) | Receive mode | 0 | | | ns |
| | Transmit mode | 300 | | | |
| $t_{(\text{SU:DAT})}$ Data setup time (see Figure 1) | | 250 | | | ns |
| $t_{(\text{TIMEOUT})}$ Error signal/detect (see Figure 1) | See ⁽¹⁾ | 25 | | 35 | μs |
| $t_{(\text{LOW})}$ Clock low period (see Figure 1) | | 4.7 | | | μs |
| $t_{(\text{HIGH})}$ Clock high period (see Figure 1) | See ⁽²⁾ | 4 | | 50 | μs |
| $t_{(\text{LOW:SEXT})}$ Cumulative clock low slave extend time | See ⁽³⁾ | | | 25 | μs |
| $t_{(\text{LOW:MEXT})}$ Cumulative clock low master extend time (see Figure 1) | See ⁽⁴⁾ | | | 10 | μs |
| t_f Clock/data fall time | See ⁽⁵⁾ | | | 300 | ns |
| t_r Clock/data rise time | See ⁽⁶⁾ | | | 1000 | ns |

 (1) The bq8040 times out when any clock low exceeds $t_{(\text{TIMEOUT})}$.

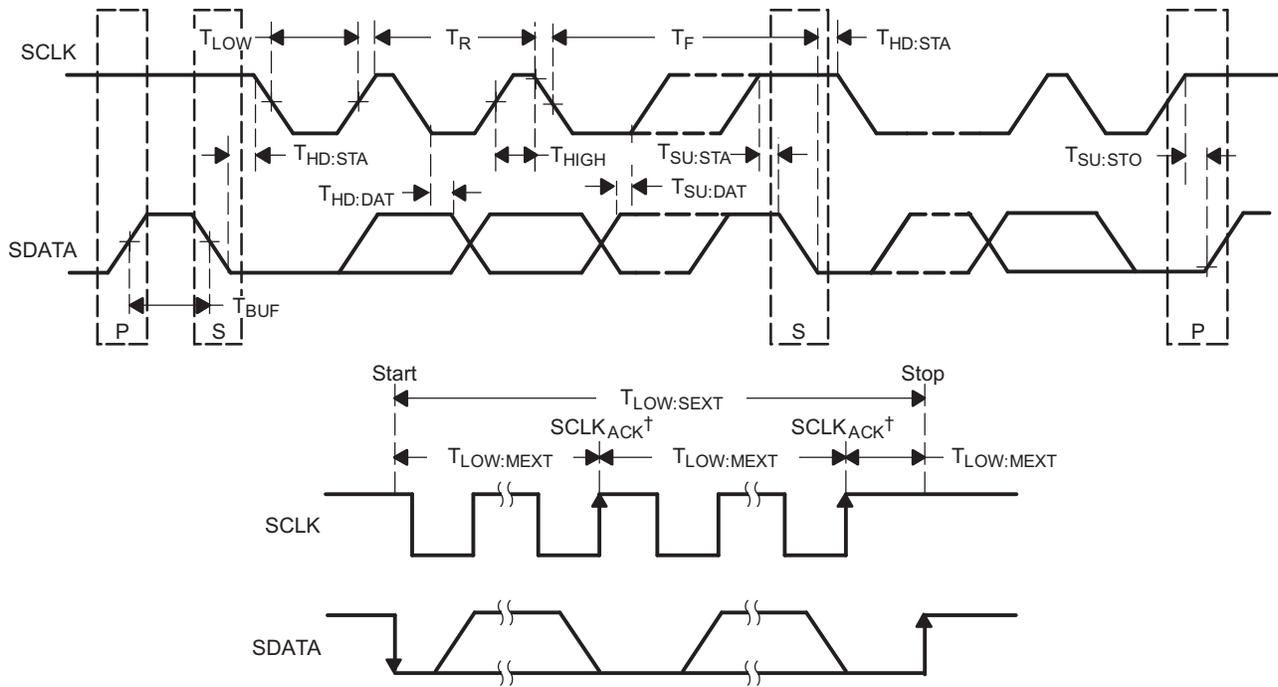
 (2) $t_{(\text{HIGH})}$, Max, is the minimum bus idle time. SMBC = SMBD = 1 for $t > 50\text{ ms}$ causes reset of any transaction involving bq8040 that is in progress. This specification is valid when the NC_SMB control bit remains in the default cleared state (CLK[0]=0).

 (3) $t_{(\text{LOW:SEXT})}$ is the cumulative time a slave device is allowed to extend the clock cycles in one message from initial start to the stop.

 (4) $t_{(\text{LOW:MEXT})}$ is the cumulative time a master device is allowed to extend the clock cycles in one message from initial start to the stop.

 (5) Rise time $t_r = \text{VILMAX} - 0.15$ to $(\text{VIHMIN} + 0.15)$

 (6) Fall time $t_f = 0.9V_{\text{DD}}$ to $(\text{VILMAX} - 0.15)$



A. SCLKACK is the acknowledge-related clock pulse generated by the master.

Figure 1. SMBus Timing Diagram

FEATURE SET

Primary (1st Level) Safety Features

The bq20z95 supports a wide range of battery and system protection features that can easily be configured. The primary safety features include:

- Cell over/under voltage protection
- Charge and Discharge over current
- Short Circuit
- Charge and Discharge Over temperature
- AFE Watchdog

Secondary (2nd Level) Safety Features

The secondary safety features of the bq20z95 can be used to indicate more serious faults via the SAFE (pin 7). This pin can be used to blow an in-line fuse to permanently disable the battery pack from charging or discharging. The secondary safety protection features include:

- Safety over voltage
- Safety over current in Charge and Discharge
- Safety over temperature in Charge and Discharge
- Charge FET and 0 Volt Charge FET fault
- Discharge FET fault
- AFE communication fault

Charge Control Features

The bq20z95 charge control features include:

- Reports the appropriate charging current needed for constant current charging and the appropriate charging voltage needed for constant voltage charging to a smart charger using SMBus broadcasts.
- Determines the chemical state of charge of each battery cell using Impedance Track™ and can reduce the charge difference of the battery cells in fully charged state of the battery pack gradually using cell balancing algorithm during charging. This prevents fully charged cells from overcharging and causing excessive degradation and also increases the usable pack energy by preventing premature charge termination
- Supports pre-charging/zero-volt charging
- Support fast charging
- Supports charge inhibit and charge suspend if battery pack temperature is out of temperature range
- Reports charging fault and also indicate charge status via charge and discharge alarms.

Gas Gauging

The bq20z95 uses the Impedance Track™ Technology to measure and calculate the available charge in battery cells. The achievable accuracy is better than 1% error over the lifetime of the battery and there is no full charge discharge learning cycle required.

See *Theory and Implementation of Impedance Track Battery Fuel-Gauging Algorithm* application note (SLUA364) for further details.

Authentication

The bq20z95 supports authentication by the host using SHA-1.

Power Modes

The bq20z95 supports 3 different power modes to reduce power consumption:

- In Normal Mode, the bq20z95 performs measurements, calculations, protection decisions and data updates in 1 second intervals. Between these intervals, the bq20z95 is in a reduced power stage.
- In Sleep Mode, the bq20z95 performs measurements, calculations, protection decisions and data update in adjustable time intervals. Between these intervals, the bq20z95 is in a reduced power stage. The bq20z95 has a wake function that enables exit from Sleep mode, when current flow or failure is detected.
- In Shutdown Mode the bq20z95 is completely disabled.

CONFIGURATION

Oscillator Function

The bq20z95 fully integrates the system oscillators. Therefore the bq20z95 requires no external components for this feature.

System Present Operation

The bq20z95 checks the $\overline{\text{PRES}}$ pin periodically (1s). If $\overline{\text{PRES}}$ input is pulled to ground by external system, the bq20z95 detects this as system present.

BATTERY PARAMETER MEASUREMENTS

The bq20z95 uses an integrating delta-sigma analog-to-digital converter (ADC) for current measurement, and a second delta-sigma ADC for individual cell and battery voltage, and temperature measurement.

Charge and Discharge Counting

The integrating delta-sigma ADC measures the charge/discharge flow of the battery by measuring the voltage drop across a small-value sense resistor between the SR1 and SR2 pins. The integrating ADC measures bipolar signals from -0.25 V to 0.25 V. The bq20z95 detects charge activity when $V_{\text{SR}} = V_{(\text{SRP})} - V_{(\text{SRN})}$ is positive and discharge activity when $V_{\text{SR}} = V_{(\text{SRP})} - V_{(\text{SRN})}$ is negative. The bq20z95 continuously integrates the signal over time, using an internal counter. The fundamental rate of the counter is 0.65 nVh.

Voltage

The bq20z95 updates the individual series cell voltages at one second intervals. The internal ADC of the bq20z95 measures the voltage, scales and calibrates it appropriately. This data is also used to calculate the impedance of the cell for the Impedance Track™ gas-gauging.

Current

The bq20z95 uses the SRP and SRN inputs to measure and calculate the battery charge and discharge current using a 5 mΩ to 20 mΩ typ. sense resistor.

Auto Calibration

The bq20z95 provides an auto-calibration feature to cancel the voltage offset error across SRN and SRP for maximum charge measurement accuracy. The bq20z95 performs auto-calibration when the SMBus lines stay low continuously for a minimum of 5 s.

Temperature

The bq20z95 has an internal temperature sensor and 2 external temperature sensor inputs TS1 and TS2 used in conjunction with two identical NTC thermistors (default are Semitec 103AT) to sense the battery environmental temperature. The bq20z95 can be configured to use internal or up to 2 external temperature sensors.

COMMUNICATIONS

The bq20z95 uses SMBus v1.1 with Master Mode and package error checking (PEC) options per the SBS specification.

SMBus On and Off State

The bq20z95 detects an SMBus off state when SMBC and SMBD are logic-low for ≥ 2 seconds. Clearing this state requires either SMBC or SMBD to transition high. Within 1 ms, the communication bus is available.

SBS Commands

Table 1. SBS COMMANDS

| SBS Cmd | Mode | Name | Format | Size in Bytes | Min Value | Max Value | Default Value | Unit |
|---------|------|------------------------|--------------|---------------|-----------|-----------|-------------------|--------------|
| 0x00 | R/W | ManufacturerAccess | hex | 2 | 0x0000 | 0xffff | — | |
| 0x01 | R/W | RemainingCapacityAlarm | unsigned int | 2 | 0 | 65535 | — | mAh or 10mWh |
| 0x02 | R/W | RemainingTimeAlarm | unsigned int | 2 | 0 | 65535 | — | min |
| 0x03 | R/W | BatteryMode | hex | 2 | 0x0000 | 0xffff | — | |
| 0x04 | R/W | AtRate | signed int | 2 | -32768 | 32767 | — | mA or 10mW |
| 0x05 | R | AtRateTimeToFull | unsigned int | 2 | 0 | 65535 | — | min |
| 0x06 | R | AtRateTimeToEmpty | unsigned int | 2 | 0 | 65535 | — | min |
| 0x07 | R | AtRateOK | unsigned int | 2 | 0 | 65535 | — | |
| 0x08 | R | Temperature | unsigned int | 2 | 0 | 65535 | — | 0.1°K |
| 0x09 | R | Voltage | unsigned int | 2 | 0 | 20000 | — | mV |
| 0x0a | R | Current | signed int | 2 | -32768 | 32767 | — | mA |
| 0x0b | R | AverageCurrent | signed int | 2 | -32768 | 32767 | — | mA |
| 0x0c | R | MaxError | unsigned int | 1 | 0 | 100 | — | % |
| 0x0d | R | RelativeStateOfCharge | unsigned int | 1 | 0 | 100 | — | % |
| 0x0e | R | AbsoluteStateOfCharge | unsigned int | 1 | 0 | 100 | — | % |
| 0x0f | R/W | RemainingCapacity | unsigned int | 2 | 0 | 65535 | — | mAh or 10mWh |
| 0x10 | R | FullChargeCapacity | unsigned int | 2 | 0 | 65535 | — | mAh or 10mWh |
| 0x11 | R | RunTimeToEmpty | unsigned int | 2 | 0 | 65535 | — | min |
| 0x12 | R | AverageTimeToEmpty | unsigned int | 2 | 0 | 65535 | — | min |
| 0x13 | R | AverageTimeToFull | unsigned int | 2 | 0 | 65535 | — | min |
| 0x14 | R | ChargingCurrent | unsigned int | 2 | 0 | 65535 | — | mA |
| 0x15 | R | ChargingVoltage | unsigned int | 2 | 0 | 65535 | — | mV |
| 0x16 | R | BatteryStatus | unsigned int | 2 | 0x0000 | 0xffff | — | |
| 0x17 | R/W | CycleCount | unsigned int | 2 | 0 | 65535 | — | |
| 0x18 | R/W | DesignCapacity | unsigned int | 2 | 0 | 65535 | — | mAh or 10mWh |
| 0x19 | R/W | DesignVoltage | unsigned int | 2 | 7000 | 16000 | 14400 | mV |
| 0x1a | R/W | SpecificationInfo | unsigned int | 2 | 0x0000 | 0xffff | 0x0031 | |
| 0x1b | R/W | ManufactureDate | unsigned int | 2 | 0 | 65535 | 0 | |
| 0x1c | R/W | SerialNumber | hex | 2 | 0x0000 | 0xffff | 0x0001 | |
| 0x20 | R/W | ManufacturerName | String | 11+1 | — | — | Texas Instruments | ASCII |
| 0x21 | R/W | DeviceName | String | 7+1 | — | — | bq20z95 | ASCII |
| 0x22 | R/W | DeviceChemistry | String | 4+1 | — | — | LION | ASCII |
| 0x23 | R | ManufacturerData | String | 14+1 | — | — | — | ASCII |
| 0x2f | R/W | Authenticate | String | 20+1 | — | — | — | ASCII |

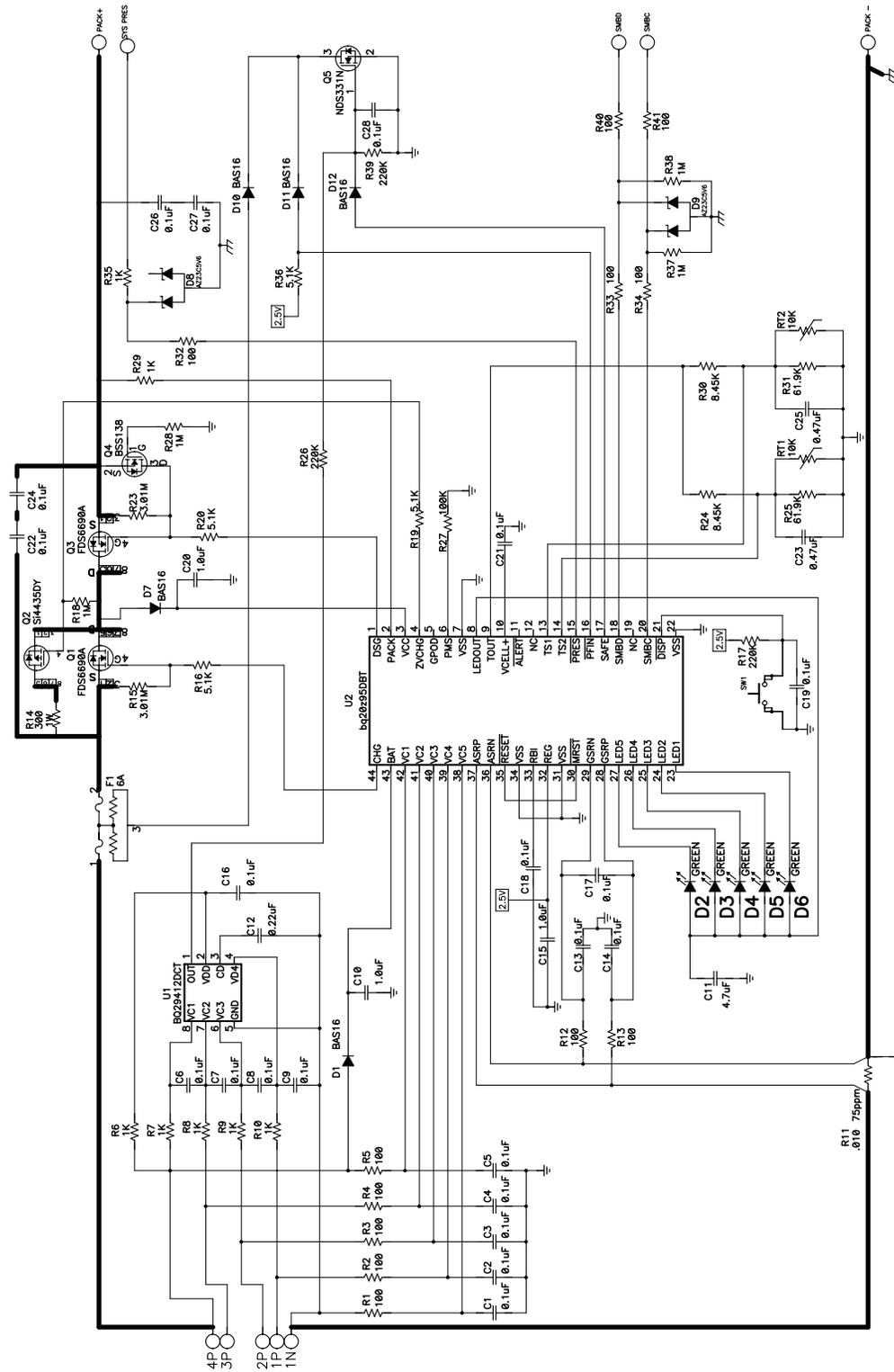
Table 1. SBS COMMANDS (continued)

| SBS Cmd | Mode | Name | Format | Size in Bytes | Min Value | Max Value | Default Value | Unit |
|---------|------|--------------|--------------|---------------|-----------|-----------|---------------|------|
| 0x3c | R | CellVoltage4 | unsigned int | 2 | 0 | 65535 | — | mV |
| 0x3d | R | CellVoltage3 | unsigned int | 2 | 0 | 65535 | — | mV |
| 0x3e | R | CellVoltage2 | unsigned int | 2 | 0 | 65535 | — | mV |
| 0x3f | R | CellVoltage1 | unsigned int | 2 | 0 | 65535 | — | mV |

Table 2. EXTENDED SBS COMMANDS

| SBS Cmd | Mode | Name | Format | Size in Bytes | Min Value | Max Value | Default Value | Unit |
|---------|------|------------------------|--------------|---------------|------------|------------|---------------|-------|
| 0x45 | R | AFEData | String | 11+1 | — | — | — | ASCII |
| 0x46 | R/W | FETControl | hex | 1 | 0x00 | 0xff | — | |
| 0x4f | R | StateOfHealth | unsigned int | 1 | 0 | 100 | — | % |
| 0x51 | R | SafetyStatus | hex | 2 | 0x0000 | 0xffff | — | |
| 0x53 | R | PFStatus | hex | 2 | 0x0000 | 0xffff | — | |
| 0x54 | R | OperationStatus | hex | 2 | 0x0000 | 0xffff | — | |
| 0x55 | R | ChargingStatus | hex | 2 | 0x0000 | 0xffff | — | |
| 0x57 | R | ResetData | hex | 2 | 0x0000 | 0xffff | — | |
| 0x5a | R | PackVoltage | unsigned int | 2 | 0 | 65535 | — | mV |
| 0x5d | R | AverageVoltage | unsigned int | 2 | 0 | 65535 | — | mV |
| 0x60 | R/W | UnSealKey | hex | 4 | 0x00000000 | 0xffffffff | — | |
| 0x61 | R/W | FullAccessKey | hex | 4 | 0x00000000 | 0xffffffff | — | |
| 0x62 | R/W | PFKey | hex | 4 | 0x00000000 | 0xffffffff | — | |
| 0x63 | R/W | AuthenKey3 | hex | 4 | 0x00000000 | 0xffffffff | — | |
| 0x64 | R/W | AuthenKey2 | hex | 4 | 0x00000000 | 0xffffffff | — | |
| 0x65 | R/W | AuthenKey1 | hex | 4 | 0x00000000 | 0xffffffff | — | |
| 0x66 | R/W | AuthenKey0 | hex | 4 | 0x00000000 | 0xffffffff | — | |
| 0x70 | R/W | ManufacturerInfo | String | 31+1 | — | — | — | |
| 0x71 | R/W | SenseResistor | unsigned int | 2 | 0 | 65535 | — | μΩ |
| 0x77 | R/W | DataFlashSubClassID | hex | 2 | 0x0000 | 0xffff | — | |
| 0x78 | R/W | DataFlashSubClassPage1 | hex | 32 | — | — | — | |
| 0x79 | R/W | DataFlashSubClassPage2 | hex | 32 | — | — | — | |
| 0x7a | R/W | DataFlashSubClassPage3 | hex | 32 | — | — | — | |
| 0x7b | R/W | DataFlashSubClassPage4 | hex | 32 | — | — | — | |
| 0x7c | R/W | DataFlashSubClassPage5 | hex | 32 | — | — | — | |
| 0x7d | R/W | DataFlashSubClassPage6 | hex | 32 | — | — | — | |
| 0x7e | R/W | DataFlashSubClassPage7 | hex | 32 | — | — | — | |
| 0x7f | R/W | DataFlashSubClassPage8 | hex | 32 | — | — | — | |

Application Schematic



PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| BQ20Z95DBT | ACTIVE | TSSOP | DBT | 44 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR |
| BQ20Z95DBTG4 | ACTIVE | TSSOP | DBT | 44 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR |
| BQ20Z95DBTR | ACTIVE | TSSOP | DBT | 44 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR |
| BQ20Z95DBTRG4 | ACTIVE | TSSOP | DBT | 44 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

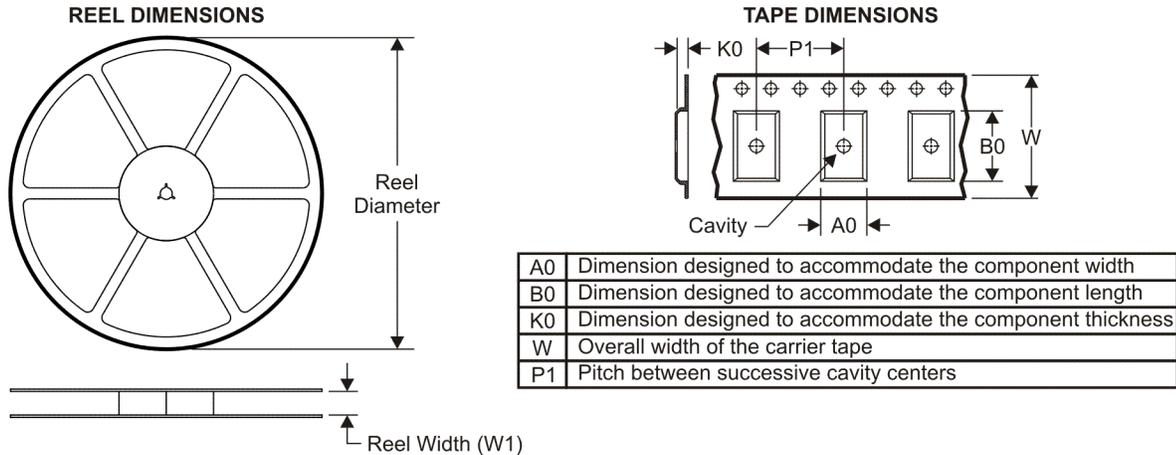
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

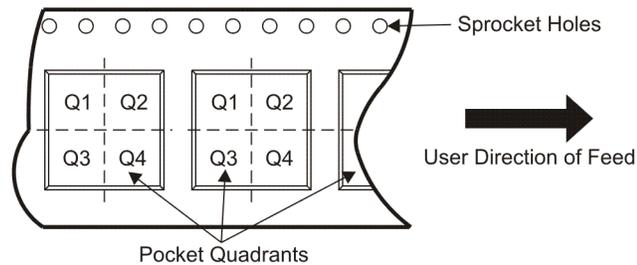
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TAPE AND REEL INFORMATION



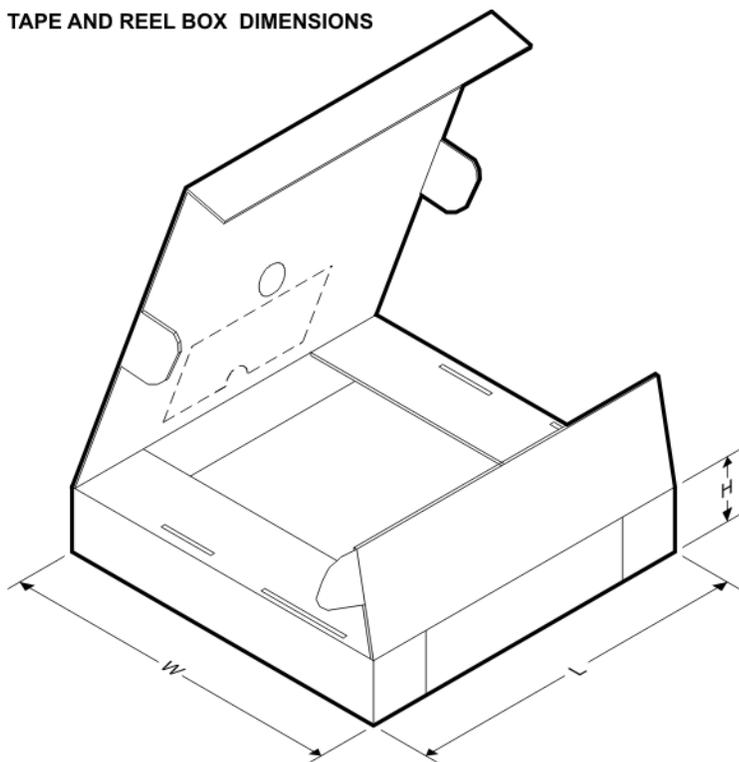
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| BQ20Z95DBTR | TSSOP | DBT | 44 | 2000 | 330.0 | 24.4 | 6.8 | 11.7 | 1.6 | 12.0 | 24.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| BQ20Z95DBTR | TSSOP | DBT | 44 | 2000 | 346.0 | 346.0 | 41.0 |

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